App. Serial No. 10/574,065 Docket No. US030375US2

## In the Specification:

Please amend paragraph 0021 of the published version of the instant application as follows.

[0021] Though the above has described in detail the preferred embodiments according to the present invention, it shall be appreciated that numerous changes, modifications and adaptations are possible to the those skilled in the art without departing the spirit of the present invention. For example, the SOI device may be a NMOS device instead of PMOS device, and the field plate 32 may be an extension, or connected to, the gate electrode 36 (as shown by dashed lines 37 in FIG. 1) instead of the source region 42, Thus, the scope of the invention is intent to be solely defined in the accompanying claims